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Optical Properties of Yb: Lu₃Al₅O₁₂ Crystal Irradiated by 4.5-MeV Si Ions

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Compact waveguide laser sources emitting at wavelength around $1.0\,\mu m$ are interesting in a multiple of application. In present work, we demonstrate a crystalline waveguide in Yb:Lu₃Al₅O₁₂ (Yb:LuAG) crystal irradiated by 4.5-MeV Si ions at fluences of $1.0\cdot 10^{15}\, cm^{-2}$. A typical "barrier-confined" waveguide geometry is confirmed by performing the prism-coupling measurement at a wavelength of 632.8 nm with transverse electric (TE) polarization, and the refractive index profile is proposed based on the dark-mode plots. Under excitation at 930 nm, the peak emission at 1030 nm is generated with a bandwidth of 14.4 nm. The fluorescence decay actions are investigated on a Jobin Yvon spectrometer. The radiative constants and peak emission cross-section values are obtained.

Keywords: Yb, Lu₃Al₅O₁₂, ion irradiation, optical waveguide, photoluminescence spectroscopy.